



Product Summary

The ZMS030N06HP combines advanced trench MOSFET technology with a low resistance package to provide extremely low $R_{DS(ON)}$.



m PJ

I nB M

c QJ

device constructure

$R_{DS(ON)}$ to minimize conduction loss

fast switching



Synchronous Rectification for AC-DC/DC-DC converter

Oring switches

Power Tools

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i H	gmJM JP
g	gmJM JP
c	BULK TUBE
B	500

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$T_c = 25$

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	$I_{D@TC=25}$	150	A
	$I_{D@TC=75}$	114	A
	$I_{D@TC=100}$	94	A
Pulsed Drain Current	I_{DM}	400	A
Total Power Dissipation($TC=25$)	$P_{D@TC=25}$	150	W
Operating Junction Temperature	T_J	-55 to 150	
Storage Temperature	T_{STG}	-55 to 150	
Single Pulse Avalanche Energy	E_{AS}	1200	mJ



Thermal resistance

Parameter	Symbol	Min.	Typ.	Max.	Unit
Thermal resistance, junction - case	R _{thJC}	-	-	0.75	° C/W
Thermal resistance, junction - ambient	R _{thJA}	-	-	70	° C/W
Soldering temperature, wavesoldering for 10s	T _{sold}				


